Introduction

The Virtex®-6 FPGA memory interface solutions cores provide high-performance connections to DDR3 and DDR2 SDRAMs, QDR II+ SRAM, and RLDRAM II devices. For information about the QDR II+ SRAM, see QDR II+ SRAM, page 4. For information about RLDRAM II devices, see RLDRAM II Memory, page 6.

DDR3 and DDR2 SDRAMs

This section discusses the features, applications, and functional description of Virtex-6 FPGA memory interface solutions in DDR3 and DDR2 SDRAMs. These solutions are available with an optional AXI4 slave interface.

DDR3 SDRAM Features

- 303–533 MHz (606–1066 Mb/s) performance for center column, single-rank interfaces up to 72 bits wide:
  - 400 MHz in a -1 commercial speed grade device
  - 533 MHz in a -2 commercial speed grade device
  - 533 MHz in a -3 commercial speed grade device
- 303 MHz (606 Mb/s) performance (pending characterization) for dual-rank interfaces up to 72 bits wide
- Hardware validated
- Component support for interface widths up to 144 bits
- Single- and dual-rank UDIMM, SODIMM, and RDIMM support
- 2 Gb density device support (additional densities supported in the MIG tool using the Create Custom Part feature)
- 8-bank support
- x4, x8, and x16 device support
- 4:1 and 8:1 DQ:DQS ratio support
- Configurable data bus widths (multiples of 8, up to 144 bits)
- 4-word, 8-word, and “On the Fly” (OTF) burst support

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Design Tool Requirements

- HDL Synthesis XST 13.1, Synopsys Synplify Pro E-2011.03
- Xilinx Implementation Tools ISE® Design Suite 13.1
- Simulation Mentor Graphics ModelSim 6.6d

Support

Provided by Xilinx, Inc. @www.xilinx.com/support

Notes:
1. This is a 72-bit design. Resource utilization can change depending on the options chosen, or memory device used, or both.
2. Maximum frequency listed. Implementations might be limited by FPGA column selection and interface data width. Consult the MIG tool and UG406, Virtex-6 FPGA Memory Interface Solutions User Guide for more information.

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• Support for 5 to 9 cycles of column-address strobe (CAS) latency (CL)
• On-die termination (ODT) support
• Support for 5 to 8 cycles of CAS write latency (CWL)
• ZQ calibration – initial and periodic (configurable)
• ECC support
• Write leveling support for DDR3 (fly-by routing topology required for DDR3 component designs)
• JEDEC-compliant DDR3 initialization support
• Source code delivery in Verilog or VHDL
• 2:1 memory to FPGA logic interface clock ratio
• Two controller request processing modes:
  • Normal: reorder requests to optimize system throughput and latency
  • Strict: memory requests are processed in the order received
• Multiple controllers per FPGA supported through the Memory Interface Generator (MIG) tool

**DDR2 SDRAM Features**

• 125–400 MHz (250–800 Mb/s) performance for single-rank interfaces up to 72 bits wide:
  • 400 MHz in all commercial speed grades
• 150 MHz (300 Mb/s) performance (pending characterization) for dual-rank interfaces up to 72 bits wide
• Hardware validated
• Component support for interface widths up to 144 bits
• Single-rank UDIMM, SODIMM, and RDIMM support
• 1 and 2 Gb device support (additional densities supported in the MIG tool using the Create Custom Part feature)
• 4- and 8-bank support
• x4, x8, and x16 device support
• 4:1 and 8:1 DQ:DQS ratio support
• Configurable data bus widths (multiples of 8, up to 144 bits)
• 4- and 8-word burst support
• Support for 3 to 6 cycles of CL
• ODT support
• ECC support
• JEDEC-compliant DDR2 initialization support
• Source code delivery in Verilog or VHDL.
• 2:1 memory to FPGA logic interface clock ratio
• Two controller request processing modes:
  • Normal: reorder requests to optimize system throughput and latency
  • Strict: memory requests are processed in the order received
• Multiple controllers per FPGA supported by running the MIG tool multiple times
AXI4 Slave Interface Features

- AXI4 slave-compliant memory-mapped interface.
- 1:1 clock rate to the controller.
- AXI4 interface data width can be 32, 64, 128, or 256 bits wide to correspond with memory data width of 8, 16, 32, or 64 bits.
- Parameterized address width support.
- Support for INCR burst up to 256 data beats.
- WRAP burst support.
- Optional narrow burst support. This can be excluded for optimized area.

Applications

Typical applications for the Virtex-6 FPGA memory interface solutions include the following:

- DDR2 SDRAM interfaces
- DDR3 SDRAM interfaces

Figure 1 shows a high-level block diagram of the Virtex-6 FPGA memory interface solution connecting a user design to a DDR2 or DDR3 SDRAM device. The physical layer (PHY) side of the design is connected to the DDR2 or DDR3 SDRAM device via FPGA I/O blocks (IOBs), and the user interface (UI) side is connected to the user design via FPGA logic. Alternatively, an AXI4 slave interface is available to connect to an AXI4 master (not shown in Figure 1). Refer to UG406, Virtex-6 FPGA Memory Interface Solutions User Guide for more details regarding the design.

![Virtex-6 FPGA Memory Interface Solution](DS186_01_021209)

**Figure 1: DDR2/DDR3 SDRAM Memory Interface Solution**

Functional Description

As shown in Figure 1, the top-level functional blocks of the Virtex-6 FPGA memory interface solution include:

- The UI block:
  - Presents the user interface to a user design
  - Provides a simple and user-friendly alternative to the native interface
  - Buffers read and write data
  - Reorders read return data to match the request order
  - Presents a flat address space and translates it to the addressing required by the SDRAM
• The memory controller (MC) block:
  • Receives requests from the user design
  • Reorders requests to minimize dead states for maximum SDRAM performance
  • Manages SDRAM row/bank configuration
  • Performs high-level SDRAM management such as refresh and activate/precharge

• The PHY block:
  • Interfaces with the MC block over a simple interface and translates the signals into the actual signals sent to the SDRAM, and vice versa
  • Translates and synchronizes control and data over various clock domains
  • Initializes the SDRAM
  • Performs write leveling for DDR3 (fly-by routing topology required for component designs)
  • Interfaces with the MC to perform periodic timing calibration required to account for changing environmental conditions
  • Performs calibration to center align capture clocks with read data

Figure 1 also shows a user design connecting to the memory interface. An example user design is provided with the core. Refer to UG406, *Virtex-6 FPGA Memory Interface Solutions User Guide* for more details regarding the design.

**QDR II+ SRAM**

This section discusses the features, applications, and functional description of Virtex-6 FPGA memory interface solutions in QDR II+ SRAM.

**Features**

• QDR II+ SRAM device support
• 120–400 MHz performance:
  • 300 MHz in a -1 commercial speed grade device
  • 350 MHz in a -2 commercial speed grade device
  • 400 MHz in a -3 commercial speed grade device
• Hardware validated
• x18 and x36 memory width support
• Configurable data bus widths
• 4-word burst support
• Source code delivery in Verilog or VHDL
• 2:1 memory to FPGA logic interface clock ratio
• 2.0 and 2.5 cycle read latency support
• Fixed latency mode support
• Multiple controllers per FPGA supported through the MIG tool

Refer to the *Virtex-6 FPGA Memory Interface Solutions User Guide* for more details regarding the features listed here.
## Applications

QDR II+ SRAMs are the latest generation of QDR SRAM devices that offer high-speed data transfers on separate read and write buses on the rising and falling edges of the clock. These memory devices are used in high-performance systems as temporary data storage, such as:

- Look-up tables in networking systems
- Packet buffers in network switches
- Cache memory in high-speed computing
- Data buffers in high-performance testers

![Diagram of QDR II+ SRAM Memory Interface Core](DS186_02_031109)

### Functional Description

As shown in Figure 2, the top-level functional block is composed of a PHY that interfaces to the user and to the QDR II+ SRAM device. The PHY block:

- Translates simple user read and write commands to conform to QDR II+ SRAM protocol
- Enables the user to provide up to one read and one write transaction per clock cycle for maximum throughput
- Performs calibration to center align clocks with data
- Returns data to the user with a corresponding valid signal
- Performs periodic timing calibration required to account for changing environmental conditions
- Translates and synchronizes over various clock domains
- Implements an optimized half-frequency design that eliminates the need for a memory controller

For more details regarding this functionality, refer to [UG406, Virtex-6 FPGA Memory Interface Solutions User Guide](www.xilinx.com) provided with the core.
RLDRAM II Memory

This section discusses the features, applications, and functional description of Virtex-6 FPGA memory interface solutions in RLDRAM II devices.

Features

- RLDRAM II common I/O (CIO) memory device support
- 175–500 MHz performance for center column interfaces:
  - 350 MHz in a -1 commercial speed grade device
  - 400 MHz in a -2 commercial speed grade device
  - 500 MHz in a -3 commercial speed grade device
- Hardware validated
- x9, x18, and x36 memory width support
- Configurable data bus widths
- 4-word and 8-word burst support
- Configuration 1, 2, 3 support
- ODT support
- RLDRAM II initialization support
- Source code delivery in Verilog or VHDL
- 2:1 memory to FPGA logic interface clock ratio
- Fixed latency mode support
- Multiple controllers per FPGA supported by running the MIG tool multiple times.

Refer to UG406, Virtex-6 FPGA Memory Interface Solutions User Guide for more details regarding the features listed here.

Applications

Figure 3 shows a high-level block diagram of the Virtex-6 FPGA memory interface solution connecting a user design to an RLDRAM II device. The PHY side of the design is connected to the RLDRAM II device via FPGA IOBs, and the UI side is connected to the user design via FPGA logic. Refer to the Virtex-6 FPGA Memory Interface Solutions User Guide for more details regarding the design.

![Figure 3: RLDRAM II Memory Interface Core](DS186_03_081309)
Functional Description

As shown in Figure 3, the top-level functional blocks of the RLDRAM II memory interface solution include:

- The UI block:
  - Presents the user interface to a user design
  - Buffers commands and write data
- The MC block:
  - Receives requests from the user design
  - Processes commands in order and adheres to memory specifications
  - Performs high-level SDRAM management such as refresh and controls bank access
- The PHY block:
  - Interfaces with the MC block over a simple interface and translates the signals into the actual signals sent to the SDRAM, and vice versa
  - Performs calibration to center align clocks with data
  - Returns data to the user with a corresponding valid signal
  - Performs periodic timing calibration required to account for changing environmental conditions
  - Translates and synchronizes over various clock domains

For more details regarding this functionality, refer to UG406, Virtex-6 FPGA Memory Interface Solutions User Guide provided with the core.

General Specifications

Refer to the Virtex-6 FPGA Memory Interface Solutions User Guide for more details regarding specific banking, pin location, and internal clock resource requirements.

Verification

The Virtex-6 FPGA memory interface solutions core has been verified in simulation. Verification tests include:

- Initialization sequence
- Read calibration
- Memory read operation
- Memory write operation
- Row/bank management
Additional Resources

The following material provides additional information related to this document:

   http://www.jedec.org
2. JEDEC Standard JESD79-3E: DDR3 SDRAM, JEDEC Solid State Technology Association
   http://www.jedec.org

Revision History

The following table shows the revision history for this document:

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<th>Date</th>
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<tr>
<td>06/24/09</td>
<td>1.0</td>
<td>Initial Xilinx release.</td>
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<tr>
<td>09/16/09</td>
<td>1.1</td>
<td>• Added QDR II+ SRAM and RLDRAM II Memory to LogiCORE™ IP Facts Table.</td>
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<tr>
<td></td>
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<td>• Updated DDR3 SDRAM Features, page 1, DDR2 SDRAM Features, page 2, and Features, page 4.</td>
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<td>• Added RLDRAM II Memory, page 6.</td>
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<td>12/02/09</td>
<td>1.2</td>
<td>• Updated speed grade and source code delivery information in Features sections of DDR3 and DDR2 SDRAMS, QDR II+ SRAM, and RLDRAM II Memory.</td>
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<tr>
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<td>• Updated Core Specifics table.</td>
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<td>04/19/10</td>
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<td>• Updated LogiCORE™ IP Facts Table.</td>
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<td>• Updated DDR3 and DDR2 SDRAMs, QDR II+ SRAM, and RLDRAM II Memory.</td>
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<tr>
<td>07/23/10</td>
<td>1.4</td>
<td>Updated DDR3 and DDR2 SDRAM resources, and ISE Design Suite and ModelSim versions in LogiCORE™ IP Facts Table. Removed x9 memory width support and added 2.0 and 2.5 cycle read latency support to Features, page 4.</td>
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<tr>
<td>12/14/10</td>
<td>1.6</td>
<td>MIG 3.61 release. Removed parenthetical note about data pending characterization for single-rank interfaces from DDR3 SDRAM Features, DDR2 SDRAM Features, LogiCORE™ IP Facts Table, Features, page 4 and Features, page 6. Changed dual-rank performance from 250 Mb/s to 300 Mb/s in DDR2 SDRAM Features.</td>
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<tr>
<td>03/01/11</td>
<td>1.7</td>
<td>MIG 3.7 release with the ISE 13.1 software release. Added note 2 to LogiCORE™ IP Facts Table.</td>
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